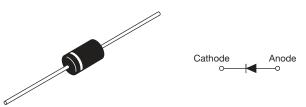
Vishay Semiconductors

Schottky Rectifier, 1.1 A



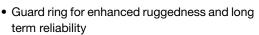
www.vishay.com

DO-204AL

PRODUCT SUMMARY					
Package	DO-204AL (DO-41)				
I _{F(AV)}	1.1 A				
V _R	90 V, 100 V				
V _F at I _F	See Electrical table				
I _{RM}	1.0 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	1.0 mJ				

FEATURES

- · Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

DESCRIPTION

The VS-11DQ... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES						
I _{F(AV)}	Rectangular waveform	1.1	А					
V _{RRM}		90/100	V					
I _{FSM}	t _p = 5 μs sine	85	А					
V _F	1 Apk, T _J = 25 °C	0.85	V					
TJ	Range	- 40 to 150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-11DQ09	VS-11DQ09-M3	VS-11DQ10	VS-11DQ10-M3	UNITS		
Maximum DC reverse voltage	V _R	90	90	100	100	V		
Maximum working peak reverse voltage	V _{RWM}	90	90	100	100	v		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS					
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T_{C} = 75 °C, rectangular waveform		1.1				
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	85	А			
See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	14				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH	1.0	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		0.5	А			

Revision: 21-Sep-11

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1



COMPLIANT

HALOGEN

FREE

Available

www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
	V _{FM} ⁽¹⁾	1 A	T ₁ = 25 °C	0.85	V		
Maximum forward voltage drop See fig. 1		2 A	1j=25 0	0.96			
		1 A	T _J = 125 °C	0.68			
		2 A	$1_{\rm J} = 125$ C	0.78			
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5	mA		
See fig. 2	IRM (')	T _J = 125 °C	V _R = naleu V _R	1.0			
Typical junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\text{C}$		35	pF		
Typical series inductance	L _S	Measured lead to lead 5 r	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µ			V/µs		

Note

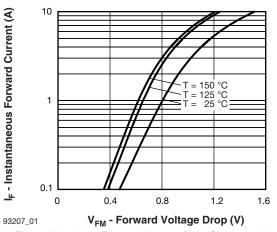
 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to ambient	R _{thJA}	R _{thJA} DC operation Without cooling fin		°C/W		
Typical thermal resistance, junction to lead	R _{thJL}	DC operation See fig. 4	81	0/10		
Approvingete weight			0.33	g		
Approximate weight			0.012	oz.		
Marking device		Case style DO-204AL (DO-41)	11DQ09			
IVIAI KII IY UEVICE		Case signe DO-204AL (DO-41)	11DQ10			

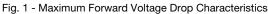
Note

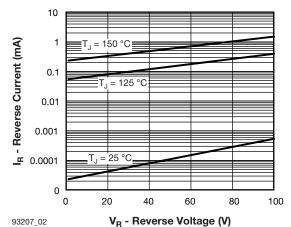
 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

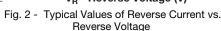
Vishay Semiconductors

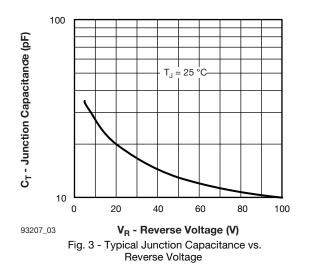


www.vishay.com









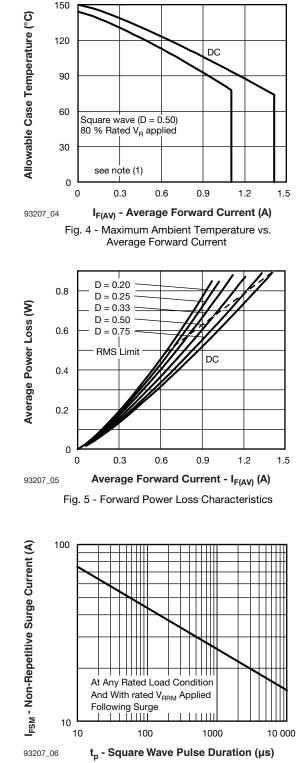


Fig. 6 - Maximum Non-Repetitive Surge Current

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

Revision: 21-Sep-11

3

Document Number: 93207

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com

								1
Device code	VS-	11	D	Q	10	TR	-M3	
		2	3	4	5	6	7	1
	1 -	Vish	ay Sem	niconduc	tors pro	duct		
	2 -	11 =	= 1.1 A (axial an	d small	packag	es - cur	rent is x 10)
	3 -	D =	DO-41	package	9			
	4 -	Q =	Schottk	xy Q se	ries		Г	
	5 -	10 =	Voltag	e ratings	s ———			09 = 90 V 10 = 100 V
	6 -	TR	= Tape	and reel	packag	е		
		Nor	e = Bul	k packa	ge			
	7 -	Env	ironmer	ntal digit				
		• No	one = Le	ead (Pb)	-free an	d RoHS	6 compl	iant
		• -N	13 = Hal	ogen-fre	e, RoH	S comp	liant, ar	nd terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-11DQ09	1000	1000	Bulk			
VS-11DQ09TR	5000	5000	Tape and reel			
VS-11DQ09-M3	1000	1000	Bulk			
VS-11DQ09TR-M3	5000	5000	Tape and reel			
VS-11DQ10	1000	1000	Bulk			
VS-11DQ10TR	5000	5000	Tape and reel			
VS-11DQ10-M3	1000	1000	Bulk			
VS-11DQ10TR-M3	5000	5000	Tape and reel			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95241				
Part marking information	www.vishay.com/doc?95304				
Packaging information	www.vishay.com/doc?95338				

4

Vishay Semiconductors

27.0 (1.06) MIN. (2 places)

1.27 (0.050) MAX.

Flash (2 places)

2.70 (0.106)

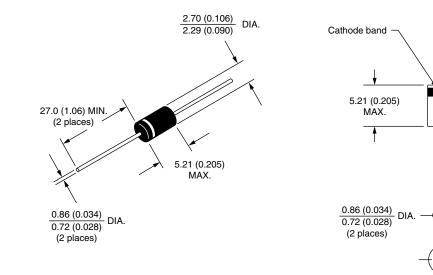
2.29 (0.090)

DIA.



Axial DO-204AL (DO-41)

DIMENSIONS in millimeters (inches)



Revision: 29-Aug-11 1 Document Number: 95241 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.